## Structural and electronic properties of multifunctional carbon composites of organometal halide perovskite

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**Table S1.** Structural and energetic properties of composites.

	Graphene/ MAPbl <sub>3</sub>	GO/ MAPbl <sub>3</sub>	C <sub>60</sub> / MAPbI <sub>3</sub>	C <sub>60</sub> (OH) <sub>24</sub> / MAPbI <sub>3</sub>
E <sub>ads</sub> [eV]	- 0.980	- 0.806	- 0.860	- 2.136
d <sub>eq</sub> [Å]	3.77	2.51	(d <sub>Pb-(C-C)</sub> ) 3.00	(d <sub>Pb-O</sub> ) 2.77

Adsorption energies ( $E_{ads}$ ) and equivalent distance ( $d_{eq}$ ) computed with PBE-D3 for PbI<sub>2</sub>-rich MAPbI<sub>3</sub> (001) surface modified with graphene, graphene oxide,  $C_{60}$  and  $C_{60}$ (OH)<sub>24</sub>.

## Table S2. Density of states analysis.

	Bulk	Slab MAPbl <sub>3</sub>	Graphen	GO	C <sub>60</sub>	C <sub>60</sub> (OH) <sub>24</sub>
	MAPbl <sub>3</sub>		е			
Eg <sup>pure</sup> [eV]	1.74/2.27	0.60/1.08	0.00/0.00	2.28/3.83	1.64/2.25	2.30/3.83
PBE-D3/HSE06-		(1×1)				
D3		0.62/1.10				
		(2×2)				
Eg <sup>composite</sup> [eV]	-	_	0.00/0.00	0.92/1.45	0.66/1.14	0.84/1.34
PBE-D3/HSE06-						
D3						
VBO [eV]	-	_	- 1.01	- 0.10	0.34	0.72
PBE-D3						

DFT band gap energies computed for pure components ( $E_g^{pure}$ ) and composite structures ( $E_g^{composite}$ ) according to PBE and HSE06 methods. Valance band offset (VBO) determined from DOS analysis according to PBE-D3 method.

**Figure S1** Isosurfaces of band decomposed charge density corresponding to valance band maximum (VBM) and conduction band minimum (CBM) according to PBE-D3 for



Colour code: Pb in green, I in violet, C in dark grey, N in blue, H in cyan, O in red.

**Figure S2** Top and side view on isosurfaces of electron charge density difference according to PBE-D3 for

**a)** graphene/ MAPbI<sub>3</sub>, **b)** GO/ MAPbI<sub>3</sub>, **c)** C<sub>60</sub>/ MAPbI<sub>3</sub> and **d)** C<sub>60</sub>(OH)<sub>24</sub>/ MAPbI<sub>3</sub> interfaces.



Dark grey (yellow) corresponds to electron charge accumulation (depletion). Colour code: Pb in green, I in violet, C in dark grey, N in blue, H in cyan, O in red.

Table S3. Charge density analysis.

	Graphene/ MAPbl <sub>3</sub>	GO/ MAPbl <sub>3</sub>	C <sub>60</sub> / MAPbl <sub>3</sub>	C <sub>60</sub> (OH) <sub>24</sub> / MAPbI <sub>3</sub>
Q <sub>Bader</sub> [e]	0.004	0.101	0.000	0.201
μ(z) [D]	- 1.42	1.58	0.83	- 0.34
<i>V</i> (z) [eV]	- 0.29	0.31	0.15	- 0.08

Charge density analysis according to PBE-D3 of graphene/ MAPbI<sub>3</sub>, GO/ MAPbI<sub>3</sub>,  $C_{60}$ / MAPbI<sub>3</sub> and  $C_{60}$ (OH)<sub>24</sub>/ MAPbI<sub>3</sub> interfaces: Bader charges ( $Q_{Bader}$ ) – positive value corresponds to the

electron charge transfer from MAPbI<sub>3</sub> to carbon nanostructure; interface dipole moment ( $\mu(z)$ ); interface electrostatic potential energy (V(z)).



Figure S3 Planar avaraged electrostatic (Hartree) potential computed with PBE-D3 for

Fermi energy is set to 0 eV.

	MAPbl <sub>3</sub>	Graphene	GO	C <sub>60</sub>	C <sub>60</sub> (OH) <sub>24</sub>
	_	(1×1)	(1×1)	(2×2)	(2×2)
IE <sup>pure</sup> [eV]	5.89 (1×1)	4.20	5.87	5.84	6.17
	5.73 (2×2)				
IE <sup>composite</sup> [eV]	-	4.45	6.38	5.67	5.57
φ <sup>pure</sup> [eV]	5.59 (1×1)	4.20	5.04	5.35	5.72
	5.32 (2×2)				
φ <sup>composite</sup> [eV]	_	4.45	5.94	5.41	5.14
-					
Δφ [eV]	-	- 1.14	0.35	0.09	- 0.18
CBO [eV]		0.00	- 2.48	- 0.16	- 0.24

Table S4. Local electrostatic (Hartree) potential analysis.

Ionization energies (IE<sup>pure</sup>, IE<sup>composite</sup>), work functions ( $φ^{pure}$ ,  $φ^{composite}$ ) and work function differences (Δφ) computed from PBE-D3 local electrostatic (Hartree) potential analysis for pure components and composites of graphene/ MAPbI<sub>3</sub>, GO/ MAPbI<sub>3</sub>, C<sub>60</sub>/ MAPbI<sub>3</sub> and C<sub>60</sub>(OH)<sub>24</sub>/ MAPbI<sub>3</sub>. The conduction band offsets (CBO) were computed as the difference in electron affinities (EAs) of heterostructure components. EAs were evaluated with the use of HSE06-D3 E<sub>g</sub> for MAPbI<sub>3</sub>, graphene and GO, while PBE-D3 E<sub>g</sub> for C<sub>60</sub> and C<sub>60</sub>(OH)<sub>24</sub>.